

**Trans IGBT Chip N-CH 600V 20A 60mW 3-Pin(2+Tab) DPAK
T/R**



Images are for reference only

[Inquiry](#)

Manufacturer:	STMicroelectronics, Inc
Package/Case:	TO252
Product Type:	Thyristors
Lifecycle:	Active

General Description

This device is a very fast IGBT developed using advanced PowerMESH™ technology. This process guarantees an excellent trade-off between switching performance and low on-state behavior. This device is well-suited for resonant or soft-switching applications.

Key Features

Low on-voltage drop (VCE(sat))

Low CRES / CIES ratio (no cross-conduction susceptibility)

Recommended For You

STGIF5CH60TS-L

STMicroelectronics, Inc
SDIP2B-26

STGIPS10K60A

STMicroelectronics, Inc
SDIP-25L

STP24NF10

STMicroelectronics, Inc
TO-220

STGW30NC120HD

STMicroelectronics, Inc
TO-247

STGIPS20K60

STMicroelectronics, Inc
SDIP-25

STB75NF75LT4

STMicroelectronics, Inc
TO-263

STD20NF06LT4

STMicroelectronics, Inc
TO-252

STGW45HF60WD

STMicroelectronics, Inc
TO-247

STGW19NC60HD

STMicroelectronics, Inc
TO-247

STGW30NC60WD

STMicroelectronics, Inc

TO-247

STGW40HI20DF2

STMicroelectronics, Inc

TO-247

STGW40V60DF

STMicroelectronics, Inc

TO-247

STGB10NC60HD

STMicroelectronics, Inc

D2PAK

STGB30V60DF

STMicroelectronics, Inc

TO-263

STGP30H60DF

STMicroelectronics, Inc

TO-220